

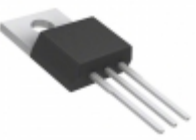
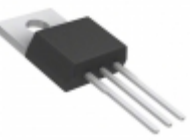



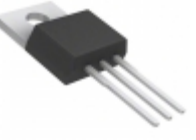
	<h2 style="color: red;">FQP34N20L</h2> <p>Hersteller-Teilenummer: FQP34N20L</p> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 200V 31A TO-220</p> <p>Datenblätter: 1.FQP34N20L.pdf 2.FQP34N20L.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 27500 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
 <p style="font-size: small;">YIC International Co., Limited.</p>	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQP34N20L
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 200V 31A TO-220
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	27500 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220-3
Verlustleistung (max)	180W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	200V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	31A (Tc)
Rds On (Max) @ Id, Vgs	75 mOhm @ 15.5A, 10V
VGS (th) (Max) @ Id	2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	72nC @ 5V
Eingabekapazität (Ciss) (Max) @ Vds	3900pF @ 25V
Verpackung	Tube

FQP34N20L ist neu im Original, Suche FQP34N20L Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQP34N20L Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQP34N20L: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQP3N30 AMI Semiconductor / ON Semiconductor MOSFET N-CH 300V 3.2A TO-220</p>	 <p>FQP33N10L Fairchild/ON Semiconductor MOSFET N-CH 100V 33A TO-220</p>	 <p>FQP3N25 Fairchild/ON Semiconductor MOSFET N-CH 250V 2.8A TO-220</p>	 <p>FQP3N25 AMI Semiconductor / ON Semiconductor MOSFET N-CH 250V 2.8A TO-220</p>
 <p>FQP34N20 AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 31A TO-220</p>	 <p>FQP3N30 Fairchild/ON Semiconductor MOSFET N-CH 300V 3.2A TO-220</p>	 <p>FQP33N10L AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 33A TO-220</p>	 <p>FQP34N20L AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 31A TO-220</p>

heiße Teile

Mehr

⊗ FQP24N40	↔ FQP27N25	⇒ FQP27N25	D FQP27N60	↔ FQP27P06
⊣ FQP27P06	⊗ FQP2N60B	D FQP2N60C	⇒ FQP2N60C	↔ FQP2N65C
⊗ FQP30N06	⊣ FQP30N06	⊗ FQP30N06L	↔ FQP30N06L	↔ FQP32N12V2
D FQP32N12V2	⊗ FQP32N20	⊣ FQP32N20C	⊗ FQP32N20C	↔ FQP33N10
⇒ FQP33N10	↔ FQP33N10L	⊗ FQP33N10L	⊣ FQP34N20	↔ FQP34N20
↔ FQP34N20L	⇒ FQP3N50C	D FQP3N60C	⊗ FQP3N60C	⊣ FQP3N80C
⊗ FQP3N80C	D FQP44N08	⇒ FQP44N08	↔ FQP44N10	↔ FQP44N10
⊣ FQP44N10F	⊗ FQP44N10F	↔ FQP45N03L	⇒ FQP45N03LM	↔ FQP45N15V2
⊗ FQP45N15V2	⊣ FQP45N20A	⊗ FQP46N15	D FQP46N15	↔ FQP47N06
↔ FQP47P06	⊗ FQP47P06	⊣ FQP47P06L	⊗ FQP47P06_	↔ FQP47P06_NW82049

Contact us: Info@Y-IC.com

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